A Novel Frequency Selective Surface with Improved Miniaturization Performance

Wanlu Li¹, Tong Zhang², Guohui Yang¹, Qun Wu¹

¹Department of Microwave Engineering, Harbin Institute of Technology, Harbin, China; ²Department of Electrical Engineering, The Fu Foundation School of Engineering and Applied Science, Columbia University, New York, USA.

Email: liwanluhit@gmail.com

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ABSTRACT

Based on previous work, a novel Frequency Selective Surface (FSS) consisting of two metallic layers is proposed. The first layer is inductive-designed to generate the band-pass performance, while the second layer is capacitive-designed so that the miniaturization characteristic can be further improved. As a result, compared with the traditional single-layer structure, the profile of the FSS proposed is relatively small with the cell’s dimension only 0.0814λ × 0.0814λ. Moreover, the structure’s stability corresponding to waves of different polarizations and incident angles are also testified, which ensures the practicability of the proposed structure.

Keywords: Frequency Selective Surface (FSS); Miniaturization; Stability

1. Introduction

Frequency selective surface (FSS) has been the subject of intensive investigation for its widespread applications as spatial microwave and optical filters for more than four decades [1-4]. It can be used in various applications, such as sub-reflectors of the frequency reuse system, band-pass radomes for radar cross-section (RCS) controlling, etc. [5-7].

The shape and dimension as well as the substrate characteristics determine the performance of the FSS. One limitation in FSS’s practical application is that there has to be enough number of unit cells so that the fabricated structure can perform approximately the same as the theoretical one. As a result, the size of the FSS usually turns out to be relatively large. Therefore, different methods have been proposed to miniaturize the cell’s profile so that more cells can be placed in a limited area in recent years [8-12].

In this paper, based on our previous work in [13], we propose a novel FSS structure consisting of two metallic layers with unique-designed pattern. With the extra conductive-designed layer, dimension of the FSS can be reduced significantly, and at the same time the FSS still remains stable responses for waves of different polarizations and incident angles.

2. FSS Structure and Characteristics

2.1. The Octagonal FSS

To form a band-pass FSS structure, the pattern we apply for the first metallic layer is improved from the complementary structure of the one in [13]. The advantage of this pattern is its excellent area utilization: it largely elongates the resonant length of the unit cell. The structure used in this paper is as Figure 1 shows, and the parameters of the pattern are listed in Table 1. Since the thickness of the dielectric substrate we choose is relatively small, according to “Babinet’s principle”, the transmission response is basically the opposite of the originally one. We simulate the transmission performances of this FSS with software CST MICROWAVE STUDIO. The results for normal incident waves are presented in Figure 2. It can be observed that for normal incident waves the resonant frequency is about 6.55 GHz for both S21 and S11, and therefore the relative dimension of the cell is about 0.131λ × 0.131λ.

2.2. The Combinational FSS

The size of the FSS’s cell can be further reduced by adding another metallic layer of the pattern presented in Figure 3. Since the octagonal part above is inductive-designed, this new part is capacitive-designed so that the resonant frequency can be further decreased. The fundamental theory of the pattern is as Figure 4 shows. The lump inside and the square loop outside together form a relatively large capacitance, and so do the outside loops of the adjacent cells. By reforming the inside part and making them intersect with each other, the area over against each other is largely increased, and therefore the equivalent capacitance increases.
Thus, by adding the additional metallic layer, the profile of the FSS’s cell can be further miniaturized. The structure of the combinational FSS is presented in Figure 5. The dimension of both the metallic layers are the same, with length \( d = 5.8 \text{ mm} \) and thickness \( t = 0.05 \text{ mm} \). Since the normal fabrication precision is about 0.2 mm, the width and gap of the metal strips we simulate is \( l = w = 0.2 \text{ mm} \). The material of the dielectric substrate is FR4, with the relative dielectric constant \( \varepsilon_r = 2.65 \), loss tangent \( \tan \delta = 0.001 \) and width \( t = 1.5 \text{ mm} \). The gap between the outside metal loop and cell boundary \( g = 0.1 \text{ mm} \).

Simulation results of the transmission performances for the additional metallic layer structure is shown in Figure 6 and for the combinational FSS is presented in Figure 7. It can be observed that the additional layer itself forms a band-stop FSS. After combination with the octagonal metallic layer, equivalent capacitance of the entire structure is increased, and as a result further improves the miniaturization performance. The resonant frequency of the combinational FSS is about 4.07 GHz for both \( S_{21} \) and \( S_{11} \) with the relative cell dimension is about \( 0.0814 \lambda \times 0.0814 \lambda \), which is approximately only 62.14\% of the octagonal FSS’s size. However, it should be noticed that because of adding another metallic layer the wide-bandwidth characteristic of the original octagonal FSS is weakened, with transmittance value of the resonant frequency decreases from –0.02 dB to –1.20 dB for \( S_{21} \) and increases from –29.50 dB to –6.23 dB for \( S_{11} \). Therefore, the combinational FSS should not be used for applications with too wide bandwidth or large-amount band-pass required.

### 2.3. Angle and Polarization Stability

Since the characteristics of the FSS should be stable for different situations, transmission performances for waves of different polarizations and incident angles are also simulated. The results for the octagonal FSS are presented in Figures 8 and 9 and for the combinational FSS are presented in Figures 10 and 11. It can be observed that for both structures with the increase of incident angles, pass bands for TE-polarized waves decrease slightly, while for TM-polarized waves increase slightly. The resonant frequencies are basically stable with the relatively deviation no more than 3.5\% in any cases. Therefore all
Figure 5. Geometry of the combinational FSS. (a) Perspective view; (b) Side view.

Figure 6. Transmission performances of the additional layer for normal incident waves.

Figure 7. Transmission performances of the combinational FSS for normal incident waves.

Figure 8. Transmission performances of the octagonal FSS for TE-polarized waves of different incident angles.

Figure 9. Transmission performances of the octagonal FSS for TM-polarized waves of different incident angles.

Figure 10. Transmission performances of the combinational FSS for TE-polarized waves of different incident angles.

Figure 11. Transmission performances of the combinational FSS for TM-polarized waves of different incident angles.

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the transmission responses remain in good states, which guarantee the practicability of the proposed FSS.

3. Conclusion

In this paper, we propose a band-pass FSS with improved miniaturization performance by adding an additional specially designed metallic layer. By this means the dimension of the unit cell can be reduced to less than two thirds of the original one, and at the same time keeping its good angle and polarization stability. Thus, the proposed FSS could become an ideal choice for practical application, and the method we used is valid and promising for future study.

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REFERENCES